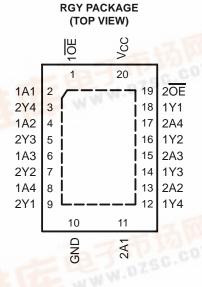
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- Optimized for 1.8-V Operation and is 3.6-V
 I/O Tolerant to Support Mixed-Mode Signal Operation
- I_{off} Supports Partial-Power-Down Mode Operation
- Sub 1-V Operable
- Max t_{pd} of 1.7 ns at 1.8 V
- Low Power Consumption, 20-μA Max ICC
- ±8-mA Output Drive at 1.8 V
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)



description/ordering information

This octal buffer/driver is operational at 0.8-V to 2.7-V V_{CC}, but is designed specifically for 1.65-V to 1.95-V V_{CC} operation.

The SN74AUC240 is designed specifically to improve the performance and density of 3-state memory address drivers, clock drivers, and bus-oriented receivers and transmitters.

This device is organized as two 4-bit buffers/drivers with separate output-enable (\overline{OE}) inputs. When \overline{OE} is low, the device passes data from the A inputs to the Y outputs. When \overline{OE} is high, the outputs are in the high-impedance state.

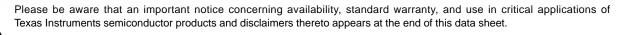
To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

This device is fully specified for partial-power-down applications using I_{off}. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

ORDERING INFORMATION

TA	PACKAGE [†]		ORDERABLE PART NUMBER	TOP-SIDE MARKING
–40°C to 85°C	QFN – RGY	QFN – RGY Tape and reel		MS240

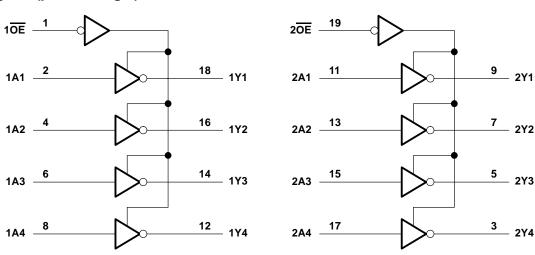
[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



FUNCTION TABLE (each 4-bit buffer/driver)

INP	JTS	OUTPUT
OE	Α	Y
L	Н	L
L	L	Н
Н	Χ	Z

logic diagram (positive logic)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC}	–0.5 V to 3.6 V
Input voltage range, V _I (see Note 1)	–0.5 V to 3.6 V
Voltage range applied to any output in the high-impedance or power-off state, VO	
(see Note 1)	–0.5 V to 3.6 V
Output voltage range, V _O (see Note 1)	-0.5 V to V _{CC} + 0.5 V
Input clamp current, I _{IK} (V _I < 0)	–50 mA
Output clamp current, I _{OK} (V _O < 0)	–50 mA
Continuous output current, I _O	±20 mA
Continuous current through V _{CC} or GND	±100 mA
Package thermal impedance, θ_{JA} (see Note 2)	37°C/W
Storage temperature range, T _{stg}	–65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

2. The package thermal impedance is calculated in accordance with JESD 51-5.



recommended operating conditions (see Note 3)

			MIN	MAX	UNIT	
VCC	Supply voltage		0.8	2.7	V	
		V _{CC} = 0.8 V	VCC			
VIН	High-level input voltage	$V_{CC} = 1.1 \text{ V to } 1.95 \text{ V}$	0.65 × V _{CC}		V	
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.7			
		V _{CC} = 0.8 V		0		
VIL	Low-level input voltage	$V_{CC} = 1.1 \text{ V to } 1.95 \text{ V}$		0.35 × V _{CC}	V	
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		0.7		
٧ _I	Input voltage	-	0	3.6	V	
\/ -	Outrotockers	Active state	0	Vcc	V	
۷O	VO Output voltage	3-state	0	3.6	V	
		V _{CC} = 0.8 V		-0.7		
		V _{CC} = 1.1 V		-3		
lOH	High-level output current	$V_{CC} = 1.4 \text{ V}$		- 5	mA	
		V _{CC} = 1.65 V		-8		
		V _{CC} = 2.3 V		-9		
		V _{CC} = 0.8 V		0.7		
		V _{CC} = 1.1 V		3		
loL	Low-level output current	V _{CC} = 1.4 V		5	mA	
		V _{CC} = 1.65 V		8		
		V _{CC} = 2.3 V		9		
Δt/Δν	Input transition rise or fall rate			20	ns/V	
TA	Operating free-air temperature	-	-40	85	°C	

NOTE 3: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

SN74AUC240 OCTAL BUFFER/DRIVER WITH 3-STATE OUTPUTS

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

P.	ARAMETER	TEST COND	ITIONS	VCC	MIN	TYP [†]	MAX	UNIT		
		I _{OH} = -100 μA		0.8 V to 2.7 V	V _{CC} -0.	1				
		$I_{OH} = -0.7 \text{ mA}$		0.8 V		0.55				
\ \/ a		$I_{OH} = -3 \text{ mA}$		1.1 V	0.8			V		
VOH		I _{OH} = -5 mA		1.4 V	1			V		
		I _{OH} = –8 mA		1.65 V	1.2					
		$I_{OH} = -9 \text{ mA}$		2.3 V	1.8					
		I _{OL} = 100 μA		0.8 V to 2.7 V			0.2			
		$I_{OL} = 0.7 \text{ mA}$		0.8 V		0.25				
\ _{\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\}		$I_{OL} = 3 \text{ mA}$		1.1 V		0.3 V				
VOL		$I_{OL} = 5 \text{ mA}$		1.4 V			0.4	V		
		$I_{OL} = 8 \text{ mA}$		1.65 V			0.45			
		I _{OL} = 9 mA		2.3 V			0.6			
lį	A and OE inputs	$V_I = V_{CC}$ or GND		0 to 2.7 V			±5	μΑ		
l _{off}		V_I or $V_O = 2.7 V$		0			±10	μΑ		
loz		$V_O = V_{CC}$ or GND		2.7 V			±10	μΑ		
Icc		$V_I = V_{CC}$ or GND,	IO = 0	0.8 V to 2.7 V			20	μΑ		
Ci	_	$V_I = V_{CC}$ or GND		2.5 V		2.5	3	pF		
Co		$V_O = V_{CC}$ or GND		2.5 V		5.5	6	pF		

[†] All typical values are at $T_A = 25$ °C.

switching characteristics over recommended operating free-air temperature range, C_L = 15 pF (unless otherwise noted) (see Figure 1)

PARAMETER	RAMETER (INPUT) (OL		V _{CC} = 0.8 V	V _{CC} =		V _{CC} =			C = 1.8 0.15 V		V _{CC} =		UNIT
	(INFOT)	(OUTPUT)	TYP	MIN	MAX	MIN	MAX	MIN	TYP	MAX	MIN	MAX	
^t pd	А	Υ	4.8	1.2	3.3	0.8	2	0.7	1.1	1.7	0.6	1.3	ns
t _{en}	OE	Υ	6.4	1.4	4	0.9	2.6	0.8	1.2	2.1	0.7	1.5	ns
^t dis	ŌĒ	Y	8.7	2	5.8	1.8	3.9	1.8	2.5	4	0.3	3	ns

switching characteristics over recommended operating free-air temperature range, C_L = 30 pF (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	٧c	C = 1.8 0.15 V	٧	V _{CC} =	2.5 V 2 V	UNIT
	(1141 01)	(0011 01)	MIN	TYP	MAX	MIN	MAX	
^t pd	А	Υ	1	1.4	2.1	0.9	1.6	ns
t _{en}	ŌĒ	Y	1.1	1.7	2.7	1	2	ns
^t dis	ŌĒ	Υ	1.9	2.5	4	1	2	ns

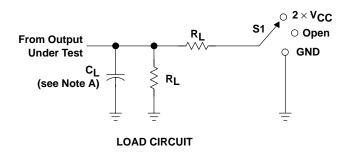


SN74AUC240 OCTAL BUFFER/DRIVER WITH 3-STATE OUTPUTS SCES430A – MARCH 2003 – REVISED MARCH 2003

operating characteristics, $T_A = 25^{\circ}C$

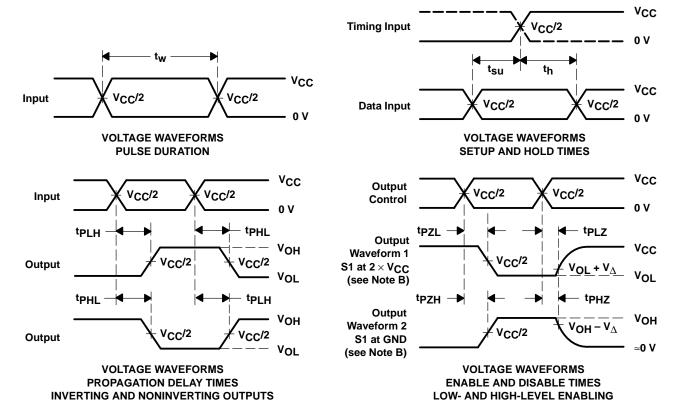
	PARAMETER		TEST	V _{CC} = 0.8 V	V _{CC} = 1.2 V	V _{CC} = 1.5 V	V _{CC} = 1.8 V	V _{CC} = 2.5 V	UNIT
	FARAMETE	N	CONDITIONS	TYP	TYP	TYP	TYP	TYP	ONIT
C _{pd}	Power	Outputs enabled	f = 10 MHz	21	21	21	22	25	pF
Фра	dissipation capacitance	Outputs disabled	1 = 10 WHZ	3	3	3	3	5	рг

PARAMETER MEASUREMENT INFORMATION



TEST	S1
tPLH/tPHL	Open
tPLZ/tPZL	2×V _{CC}
tPHZ/tPZH	GND

V _{CC}	CL	RL	$v_{\scriptscriptstyle\Delta}$
0.8 V	15 pF	2 k Ω	0.1 V
1.2 V \pm 0.1 V	15 pF	2 k Ω	0.1 V
1.5 V \pm 0.1 V	15 pF	2 k Ω	0.1 V
1.8 V \pm 0.15 V	15 pF	2 k Ω	0.15 V
2.5 V \pm 0.2 V	15 pF	2 k Ω	0.15 V
1.8 V \pm 0.15 V	30 pF	1 k Ω	0.15 V
2.5 V \pm 0.2 V	30 pF	500 Ω	0.15 V



NOTES: A. C_I includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$, slew rate \geq 1 V/ns.
- D. The outputs are measured one at a time with one transition per measurement.
- E. tpLz and tpHz are the same as tdis.
- F. tpzL and tpzH are the same as ten.
- G. tpLH and tpHL are the same as tpd.
- H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms





PACKAGE OPTION ADDENDUM

6-Dec-2005

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins P	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
SN74AUC240RGYR	ACTIVE	QFN	RGY	20	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1YEAR
SN74AUC240RGYRG4	ACTIVE	QFN	RGY	20	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1YEAR

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

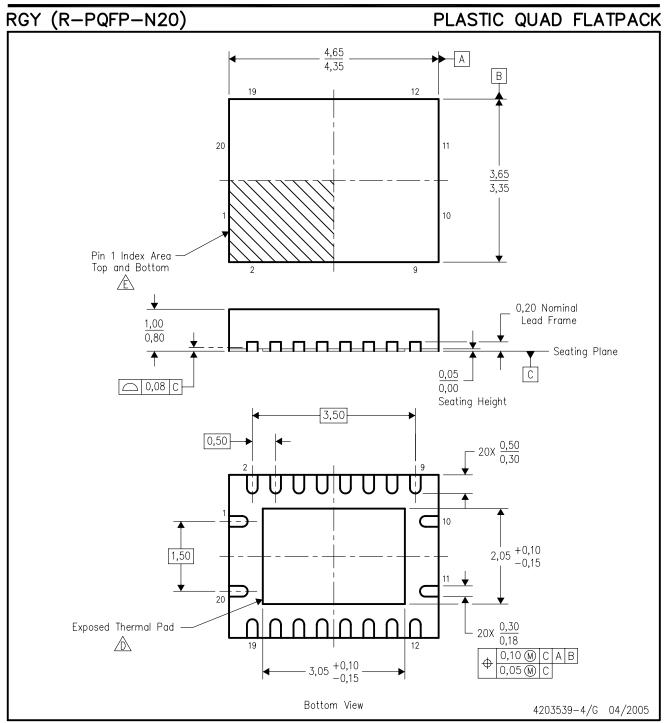
Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. QFN (Quad Flatpack No-Lead) package configuration.
- The package thermal pad must be soldered to the board for thermal and mechanical performance.
- Pin 1 identifiers are located on both top and bottom of the package and within the zone indicated. The Pin 1 identifiers are either a molded, marked, or metal feature.
- F. Package complies to JEDEC MO-241 variation BC.



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